2.5 V/3.3 V Quad Differential Driver/Receiver

NB100LVEP17

Description

The NB100LVEP17 is a 4-bit differential line receiver. The design incorporates two stages of gain, internal to the device, making it an excellent choice for use in high bandwidth amplifier applications.

The V_{BB} pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a $0.01~\mu F$ capacitor and limit current sourcing or sinking to 0.5~mA. When not used, V_{BB} should be left open.

Inputs of unused gates can be left open and will not affect the operation of the rest of the device.

Features

- Maximum Input Clock Frequency > 2.5 GHz Typical
- Maximum Input Data Rate > 2.5 Gb/s Typical
- 250 ps Typical Propagation Delay
- Low Profile QFN Package
- PECL Mode Operating Range: V_{CC} = 2.375 V to 3.8 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -2.375 V to -3.8 V
- Q Output Will Default LOW with Inputs Open or at V_{EE}
- V_{BB} Output
- These Devices are Pb-Free, Halogen Free and RoHS Compliant



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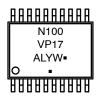
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TSSOP-20 DT SUFFIX CASE 948E 24 PIN QFN MN SUFFIX CASE 485L

MARKING DIAGRAMS*





A = Assembly Location

L = Wafer Lot
 Y = Year
 W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note <u>AND8002/D</u>.

ORDERING INFORMATION

Device	Package	Shipping [†]
NB100LVEP17DTR2G	TSSOP-20 (Pb-Free)	2500 / Tape & Reel
NB100LVEP17MNG	QFN-24 (Pb-Free)	92 Units / Tube
NB100LVEP17MNR2G	QFN-24 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

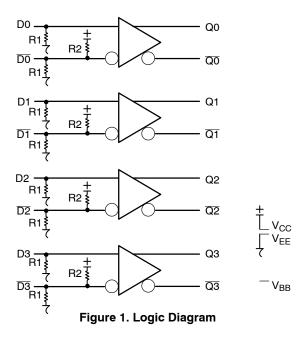
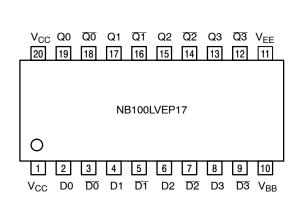


Table 1. PIN DESCRIPTION

Piı	า			Default	
TSSOP	QFN	Name	I/O	State	Description
1,20	13,18,21, 22,23	V _{CC}	-	-	Positive Supply Voltage. All $V_{\rm CC}$ Pins Must be Externally Connected to Power Supply to Guarantee Proper Operation.
11	10	V _{EE}	-	-	Negative Supply Voltage. All V _{EE} Pins Must be Externally Connected to Power Supply to Guarantee Proper Operation.
10	9	V_{BB}	-	_	ECL Reference Voltage Output.
2,4,6,8	1,3,5,7	D[0:3]	ECL Input	Low	Noninverted Differential Inputs [0:3]. Internal 75 k Ω to V _{EE} .
3,5,7,9	2,4,6,8	D[0:3]	ECL Input	High	Inverted Differential Inputs [0:3]. Internal 75 k Ω to V_{EE} and 37 k Ω to $V_{CC}.$
19,17,15,13	12,15,17,2 0	Q[0:3]	ECL Output	-	Noninverted Differential Outputs [0:3]. Typically Terminated with 50 Ω to V _{TT} = V _{CC} – 2 V.
18,16,14,12	11,14,16,1 9	Q[0:3]	ECL Output	-	Inverted Differential Outputs [0:3]. Typically Terminated with 50 Ω to V_{TT} = V_{CC} – 2 V.
N/A	24	NC	-	=	No Connect. The NC Pin is Electrically Connected to the Die and "MUST BE" Left Open.
N/A	-	EP	-		Exposed Pad. (Note 1)

^{1.} All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation. The thermally conductive expose pad on the package bottom (see case drawing) must be attached to a heat-sinking conduit.



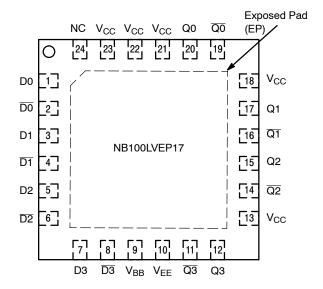


Figure 2. TSSOP-20 Lead Pinout (Top View)

Figure 3. QFN-24 Lead Pinout (Top View)

Table 2. ATTRIBUTES

Characteristics	Value
Internal Input Pulldown Resistor (R1)	75 kΩ
Internal Input Pullup Resistor (R2)	37 kΩ
ESD Protection Human Body Model Machine Model Charged Device Model	> 2 kV > 150 V > 2 kV
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	Pb-Free Pkg
TSSOP-20 QFN-24	Level 1 Level 1
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	274 Devices
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	•

^{1.} For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Mode Power Supply	V _{EE} = 0 V		6	V
V _{EE}	Negative Mode Power Supply	V _{CC} = 0 V		-6	V
V _I	Positive Mode Input Voltage Negative Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$V_{I} \leq V_{CC}$ $V_{I} \geq V_{EE}$	6 -6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
I _{BB}	V _{BB} Sink/Source			± 0.5	mA
TA	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θЈА	Thermal Resistance (Junction-to-Ambient) JEDEC 51-3 (1S - Single Layer Test Board)	0 lfpm 500 lfpm	20 TSSOP 20 TSSOP	140 50	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient) JEDEC 51-6 (2S2P Multilayer Test Board) with Filled Thermal Vias	0 lfpm 500 lfpm	24 QFN 24 QFN	37 32	°C/W °C/W
θЈС	Thermal Resistance (Junction-to-Case)	Standard Board	20 TSSOP 24 QFN	23 to 41 11	°C/W °C/W
T _{sol}	Wave Solder (Pb-Free)			265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. DC CHARACTERISTICS, PECL $V_{CC} = 2.5 \text{ V}$; $V_{EE} = 0 \text{ V}$ (Note 2)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Negative Power Supply Current	30	40	50	30	40	50	30	40	55	mA
V _{OH}	Output HIGH Voltage (Note 3)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V _{OL}	Output LOW Voltage (Note 3)	505	775	900	505	775	900	505	775	900	mV
V _{IH}	Input HIGH Voltage (Single-Ended) (Note 4)	1335		1620	1335		1620	1275		1620	mV
V _{IL}	Input LOW Voltage (Single-Ended) (Note 4)	505		875	505		875	505		875	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 5)	1.2		2.5	1.2		2.5	1.2		2.5	٧
I _{IH}	Input HIGH Current (@ V _{IH})			150			150			150	μΑ
I _{IL}	Input LOW Current (@ V _{IL}) D	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 2. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.125 V to +1.3 V.

- All loading with 50 Ω to V_{EE} = V_{CC} 2.0 V.
 Do not use V_{BB} at V_{CC} < 3.0 V.
 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 5. DC CHARACTERISTICS, PECL V_{CC} = 3.3 V; V_{EE} = 0 V (Note 6)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Negative Power Supply Current	30	40	50	30	40	50	30	40	55	mA
V _{OH}	Output HIGH Voltage (Note 7)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V _{OL}	Output LOW Voltage (Note 7)	1305	1575	1700	1305	1575	1700	1305	1575	1700	mV
V _{IH}	Input HIGH Voltage (Single-Ended)	2135		2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage (Single-Ended)	1305		1675	1305		1675	1305		1675	mV
V _{BB}	ECL Output Reference Voltage (Note 8)	1775	1875	1975	1775	1875	1975	1775	1875	1975	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 9)	1.2		3.3	1.2		3.3	1.2		3.3	V
I _{IH}	Input HIGH Current (@ V _{IH})			150			150			150	μΑ
I _{IL}	Input LOW Current (@ V _{IL}) D	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 6. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary + 0.5 V to -0.3 V.
- 7. All loading with 50 Ω to V_{CC} 2.0 V.
- 8. Single ended input operation is limited $V_{CC} \geq 3.0 \ V$ in PECL mode.
- V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 6. DC CHARACTERISTICS, NECL $V_{CC} = 0 \text{ V}$, $V_{EE} = -2.375 \text{ V}$ to -3.8 V (Note 10)

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Negative Power Supply Current	30	40	50	30	40	50	30	40	55	mA
V _{OH}	Output HIGH Voltage (Note 11)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V _{OL}	Output LOW Voltage (Note 11)	-1995	-1725	-1600	-1995	-1725	-1600	-1995	-1725	-1600	mV
V _{IH}	Input HIGH Voltage (Single-Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single-Ended)	-1995		-1600	-1995		-1600	-1995		-1600	mV
V _{BB}	ECL Output Reference Voltage (Note 12)	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 13)	V _{EE}	+ 1.2	0.0	V _{EE} ·	+ 1.2	0.0	V _{EE}	+ 1.2	0.0	V
I _{IH}	Input HIGH Current (@ V _{IH})			150			150			150	μΑ
I _{IL}	Input LOW Current (@ V _{IL}) D D	0.5 -150			0.5 -150			0.5 -150			μА

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

- 10. Input and output parameters vary 1:1 with V_{CC} .
- 11. All loading with 50 Ω to V_{CC} 2.0 V.
- 12. Single ended input operation is limited $V_{EE} \le -3.0V$ in NECL mode.
- 13. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 7. AC CHARACTERISTICS $V_{CC} = 0 \text{ V}; V_{EE} = -2.375 \text{ V to } -3.8 \text{ V or } V_{CC} = 2.375 \text{ V to } 3.8 \text{ V}; V_{EE} = 0 \text{ V (Note 14)}$

				-40°C			25°C			85°C		
Symbol	Characteristic		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{OUTPP}	Output Voltage Amplitude (See Figures 4, 5)	f _{in} < 1 GHz f _{in} = 2 GHz f _{in} = 2.5 GHz	600 400 300	700 500 400		600 325 250	700 500 400		550 300 200	700 500 400		mV
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential	D to Q, \overline{Q}	200	250	325	200	250	325	225	300	350	ps
t _{Skew}	Pulse Skew (Note 15) Within Device Skew (Note 17) Device-to-Device Skew (Note 17)			5 5 25	25 25 100		5 5 25	25 25 100		5 5 25	25 25 100	ps
t _{JITTER}	RMS Random Clock Jitter (Note 18) Peak-to Peak Data Dependent Jitter (Note 19)	f _{in} = 2.5 GHz f _{in} = 1.5 Gb/s f _{in} = 2.5 Gb/s		0.5 5 5	1 15 15		0.5 5 5	1 15 15		0.5 5 5	1 15 15	ps
V _{INPP}	Input Voltage Swing (Differential Configuration) (Note 20)		150	800	1200	150	800	1200	150	800	1200	mV
t _r t _f	Output Rise/Fall Times @ 50 MHz (20% - 80%)	Q, Q	125	175	225	140	190	240	150	200	250	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

^{14.} Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} – 2.0 V. Input edge rates 150 ps (20% – 80%).

^{15.} Pulse Skew = |t_{PLH} - t_{PHL}|
16. Worst case difference between Q0 and Q1 outputs.

^{17.} Skew is measured between outputs under identical transitions.

^{18.} Additive RMS jitter with 50% Duty Cycle Clock Signal at 2.5 GHz.
19. Peak-to-Peak jitter with input NRZ data at PRBS 2³¹-1 at 2.5 Gb/s with all inputs active.

^{20.} Input voltage swing is a single-ended measurement operating in differential mode, with minimum propagation change of 50 ps.

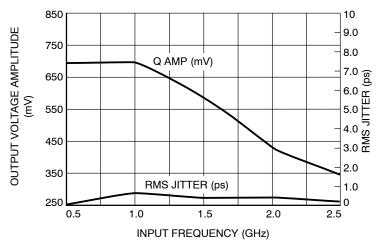


Figure 4. Output Voltage Amplitude (V_{OUTPP}) / RMS Jitter vs. Input Frequency (f_{in}) at V_{CC} = 2.5 V, Ambient Temperature

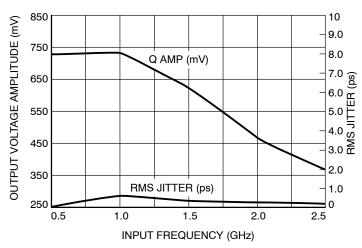


Figure 5. Output Voltage Amplitude (V_{OUTPP}) / RMS Jitter vs. Input Frequency (f_{in}) at V_{CC} = 3.3 V, Ambient Temperature

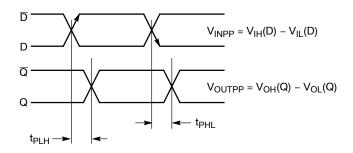


Figure 6. AC Reference Measurement

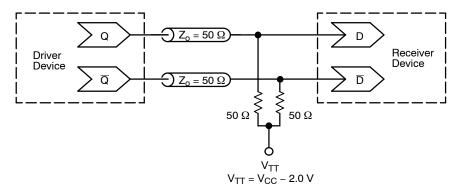


Figure 7. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide

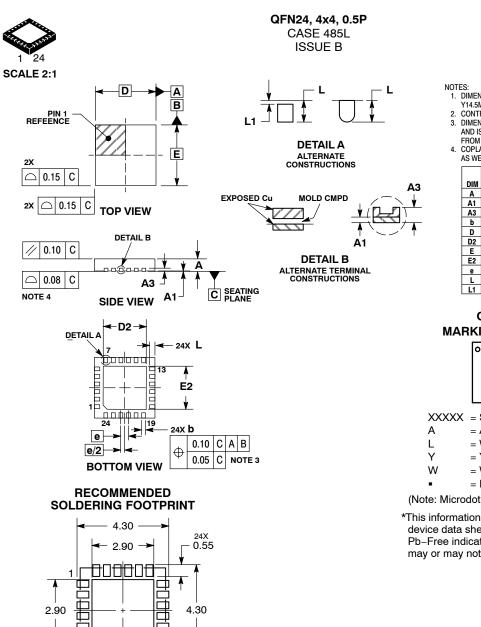
AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices



24X

DIMENSIONS: MILLIMETERS

0.32

DATE	05	II INI	2012

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 114.5M, 1994.

 2 CONTROLLING DIMENSION: MILLIMETERS.

 3 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM THE TERMINAL TIP.
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIN	IETERS			
DIM	MIN	MAX			
Α	0.80	1.00			
A1	0.00	0.05			
A3	0.20	REF			
b	0.20	0.30			
D	4.00	BSC			
D2	2.70	2.90			
E	4.00	BSC			
E2	2.70	2.90			
е	0.50 BSC				
L	0.30	0.50			
L1	0.05	0.15			

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

= Assembly Location

= Wafer Lot

= Year = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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PITCH



TSSOP-20 WB CASE 948E ISSUE D

DATE 17 FEB 2016





NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
- (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	6.40	6.60	0.252	0.260			
В	4.30	4.50	0.169	0.177			
С		1.20		0.047			
D	0.05	0.15	0.002	0.006			
F	0.50	0.75	0.020	0.030			
G	0.65	BSC	0.026 BSC				
Н	0.27	0.37	0.011	0.015			
J	0.09	0.20	0.004	0.008			
J1	0.09	0.16	0.004	0.006			
K	0.19	0.30	0.007	0.012			
K1	0.19	0.25	0.007	0.010			
L	6.40	6.40 BSC		BSC			
M	0°	8°	0°	8°			

SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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